FAIRCHILD SEMICONDUCTOR®	July 2012
FDMA7630 Single N-Channel PowerTrench <sup>®</sup> N	NOSFET
30 V, 11 A, 13 m $\Omega$ Features	General Description
<ul> <li>Max r<sub>DS(on)</sub> = 13 mΩ at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 11 A</li> <li>Max r<sub>DS(on)</sub> = 20 mΩ at V<sub>GS</sub> = 4.5 V, I<sub>D</sub> = 9 A</li> <li>Low Profile - 0.8 mm maximum - in the new package MicroFET 2x2 mm</li> <li>Free from halogenated compounds and antimony oxides</li> <li>RoHS compliant</li> </ul>	<ul> <li>This device has been designed to provide maximum efficiency and thermal performance for synchronous buck converters. The low r<sub>DS(on)</sub> and gate charge provide excellent switching performance.</li> <li>Application</li> <li>DC – DC Buck Converters</li> </ul>
Pin 1 D D G Drain Source D D S MicroFET 2X2 (Bottom View)	D D D D C C C C C C C C C C C C C C C C

# **MOSFET Maximum Ratings** $T_A = 25$ °C unless otherwise noted

Symbol		Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage			30	V	
V <sub>GSS</sub>	Gate to Source Voltage			±20	V	
1	Drain Current -Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	11		
D	-Pulsed			24	A	
D	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.4	w	
PD	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1b)	0.9	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Te	emperature Range		-55 to +150	°C	

# **Thermal Characteristics**

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	52	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	145	C/VV

# Package Marking and Ordering Information

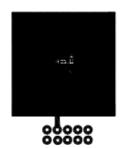
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
630	FDMA7630	MicroFET 2x2	7 "	12 mm	3000 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		15		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
On Chara	cteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C
Ū		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 11 A		10	13	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}$		14	20	mΩ
20(01)		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 11 A, T <sub>J</sub> = 125 °C		14	18	
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5 \text{ V}, \ I_{D} = 11 \text{ A}$		36		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V f = 1.0 MHz		1020	1360	pF
C <sub>oss</sub>	Output Capacitance			315	415	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			35	55	pF
R <sub>g</sub>	Gate Resistance			1.7		Ω
Switching	g Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			8	15	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 11 A		3	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		19	34	ns
t <sub>f</sub>	Fall Time	-		3	10	ns
Q <sub>q</sub>	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V		16	22	nC
Q <sub>q</sub>	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V$ $V_{DD} = 15 V$ ,		8	10	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	I <sub>D</sub> = 11 A		3.0		nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			2.2		nC
Drain-Sou	urce Diode Characteristics					
I <sub>S</sub>	Maximum Continuous Drain-Source Diod	e Forward Current			2	Α
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.8	1.2	V
t <sub>rr</sub>	Reverse Recovery Time			21	33	ns
Q <sub>rr</sub>	Reverse Recovery Charge			6	12	nC

1.  $R_{0,A}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{0,JC}$  is guaranteed by design while  $R_{0CA}$  is determined by the user's board design.

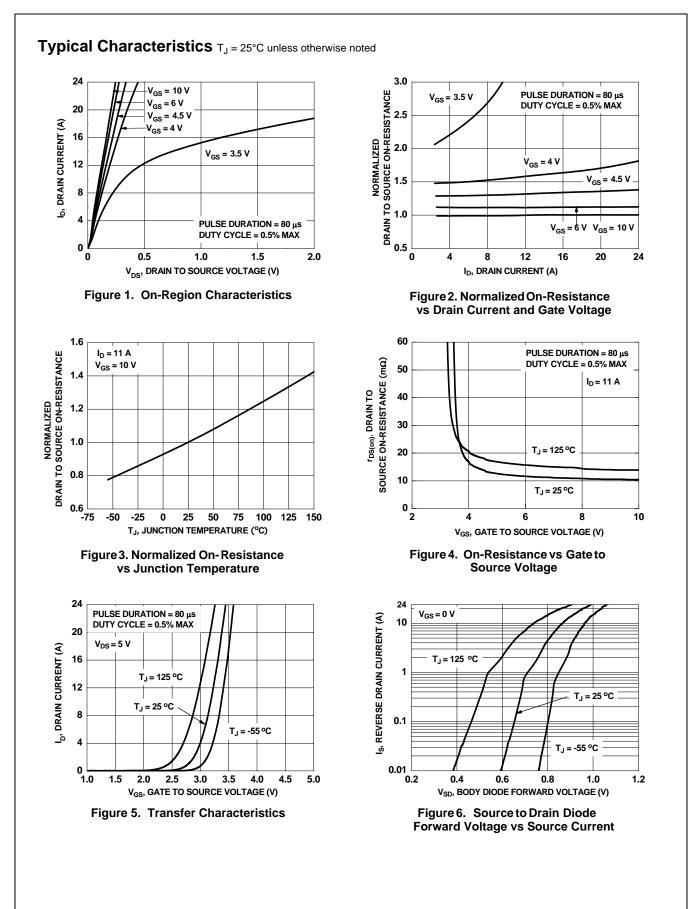


2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

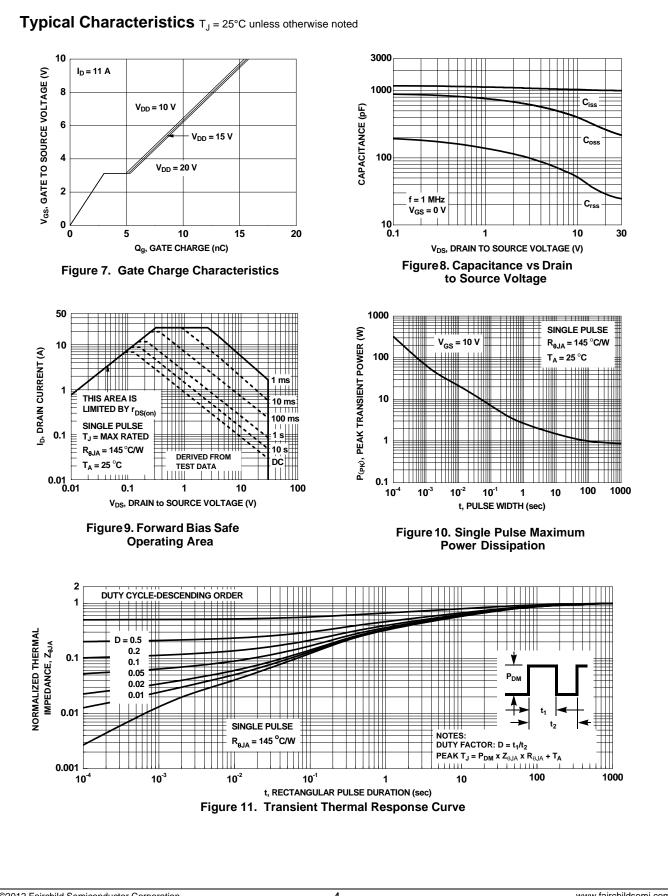
a. 52 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



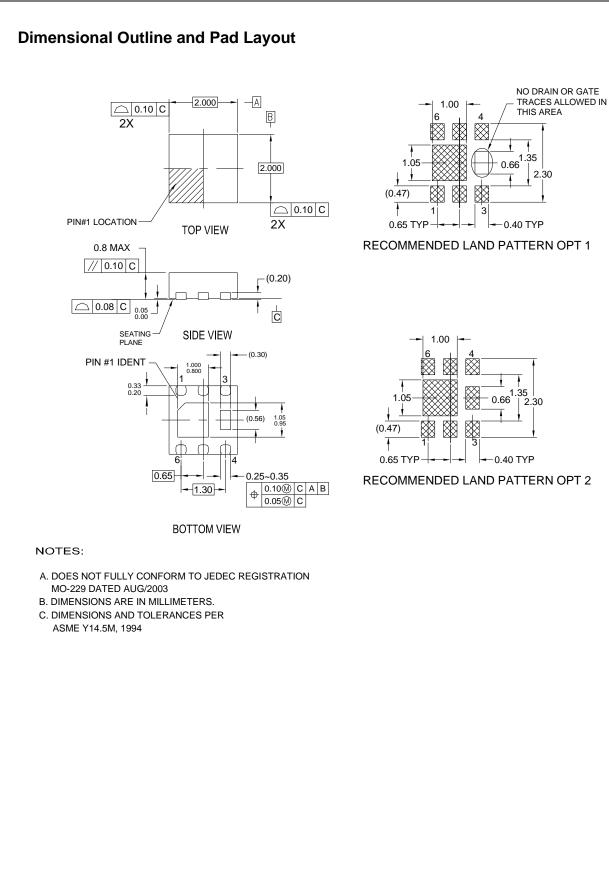
b. 145 °C/W when mounted on a minimum pad of 2 oz copper.



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